

AT-41435G Information


For Reference Only

Part Number [AT-41435G](#)
Manufacturer Broadcom Limited
Category Discrete Semiconductor Products
 [Transistors - Bipolar \(BJT\) - RF](#)
Description TRANS NPN BIPO 12V 60MA 35-SMD
Package 4-SMD (35 micro-X)
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


AT-41435G Specifications

Manufacturer Part Number	AT-41435G
Manufacturer	Broadcom Limited
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF
Package	4-SMD (35 micro-X)
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	8GHz
Noise Figure (dB Typ @ f)	1.3dB ~ 3dB @ 1GHz ~ 4GHz
Gain	10dB ~ 18.5dB
Power - Max	500mW
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 10mA, 8V
Current - Collector (Ic) (Max)	60mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	4-SMD (35 micro-X)
Supplier Device Package	35 micro-X
Report errors?	

AT-41435G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

AT-41435G Payment Methods



AT-41435G Shipping Methods



If you have any question about AT-41435G, please do not hesitate to contact us!

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